TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIII)

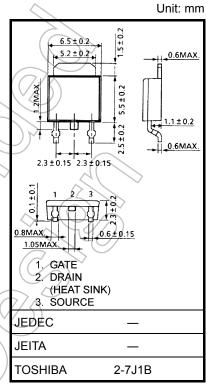
# 2SK3301

#### Switching Regulatorand DC-DC Converter Applications

- Low drain-source on-resistance:  $RDS(ON) = 15 \Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 0.65 \text{ S (typ.)}$
- Low leakage current:  $I_{DSS} = 100 \,\mu\text{A} \,(\text{max}) \,(\text{V}_{DS} = 720 \,\text{V})$
- Enhancement mode:  $V_{th} = 2.4 \text{ to } 3.4 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	900	$(\nearrow \land$
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	900	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
Gate-source voltage		$V_{GSS}$	±30	V
Drain current	DC (Note 1)	ΙD	A(	
	Pulse (Note 1)	I <sub>DP</sub>	2	Α
Drain power dissipation (Tc = 25°C)		PD	20	W
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	140	(mJ
Avalanche current		I <sub>AR</sub>	)) 1	A
Repetitive avalanche energy (Note 3)		EAR	2.0	mJ
Channel temperature		(T <sub>ch</sub> ))	150	//°C
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C

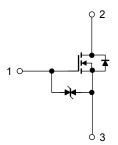


Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	6.25	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	125	°C/W



- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2:  $V_{DD} = 90 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial), L = 257 mH,  $R_G = 25 \ \Omega$ ,  $I_{AR} = 1 \ A$
- Note 3: Repetitive rating: pulse width limited by max junction temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

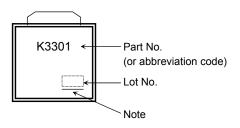
### **Electrical Characteristics (Ta = 25°C)**

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Gate-source brea	kdown voltage	V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cut-off curre	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 720 V, V <sub>GS</sub> = 0 V	/	_	100	μА
Drain-source brea	akdown voltage	V <sub>(BR)DSS</sub>	$I_D = 10$ mA, $V_{GS} = 0$ V	900	_	_	V
Gate threshold vo	oltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.4	) )	3.4	V
Drain-source ON	resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.5 A	) <u> </u>	15	20	Ω
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 0.5 A	0.3	0.65	_	S
Input capacitance	)	C <sub>iss</sub>			165	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	6	_	pF
Output capacitance		Coss		_	21	_	pF
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 0 V	- (	15	)   >	
	Turn-on time	t <sub>on</sub>			60	) —	no
	Fall time	t <sub>f</sub>		<del>(2)</del>	40	_	ns
	Turn-off time	t <sub>off</sub>	Duty ≤ 1%, t <sub>w</sub> = 10 μs		110		
Total gate charge		Qg			6		nC
(gate-source plus gate-drain)			$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 1 \text{ A}$		U		110
Gate-source charge		Qgs		_	3	_	nC
Gate-drain ("mille	Gate-drain ("miller") charge			_	3	_	nC

# Source-Drain Ratings and Characteristics (Ta = 25°C)

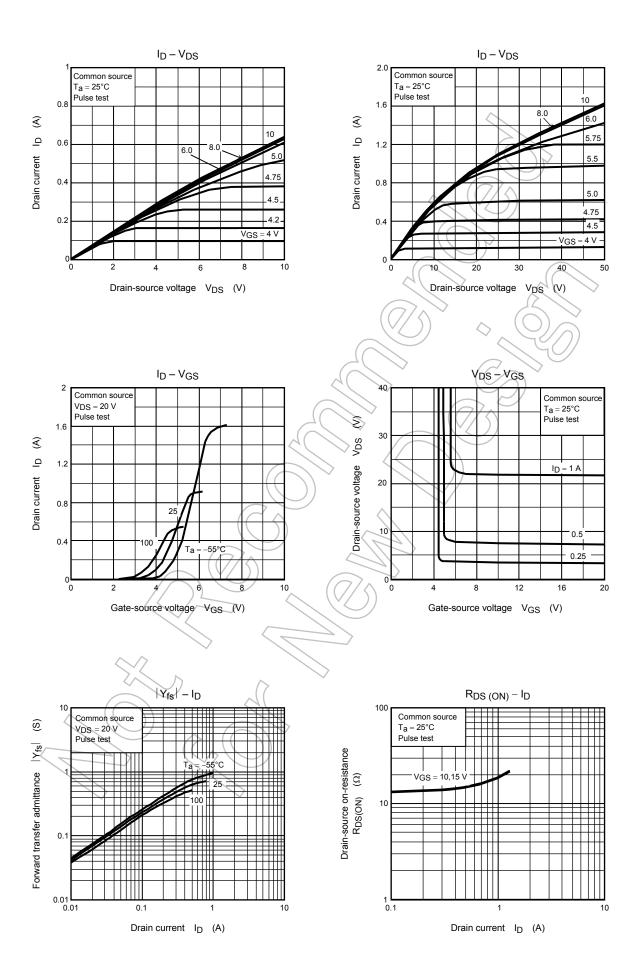
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	-	-	-	1	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_			2	А
Forward voltage (diode)	VDSF	I <sub>DR</sub> = 1 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	trr	I <sub>DR</sub> = 1 A, V <sub>GS</sub> = 0 V		1300	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dI <sub>DR</sub> /dt = 100 A/μs	_	1.95	_	μС

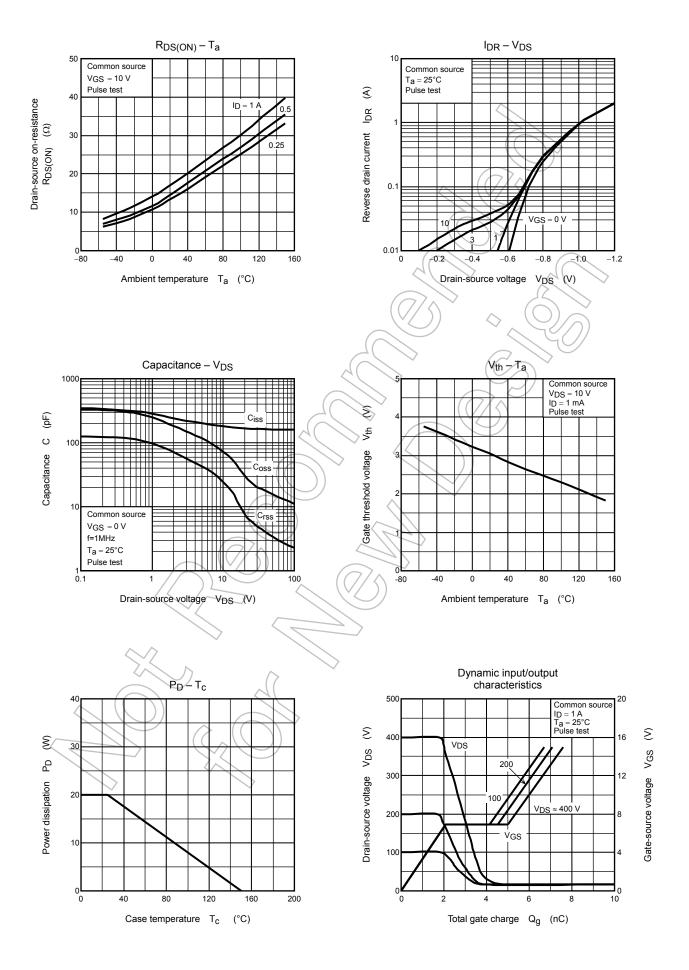
#### Marking

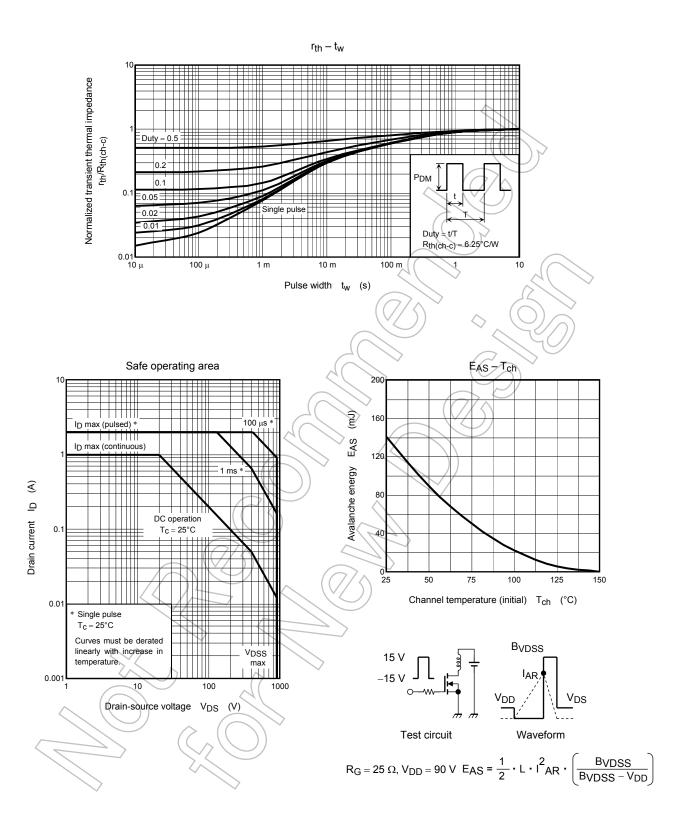


Note : A line under a Lot No. identifies the indication of product Labels
Not underlined: [[Pb]]/INCLUDES > MCV
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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